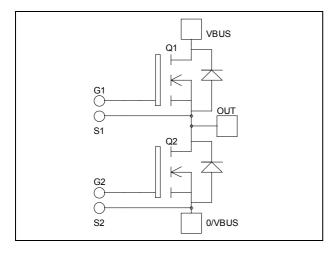


Phase leg MOSFET Power Module

$$\begin{split} V_{DSS} &= 1200 V \\ R_{DSon} &= 150 m \Omega \text{ typ } \text{ } \text{ } \text{ } \text{Tj} = 25^{\circ} \text{C} \\ I_D &= 60 \text{A} \text{ } \text{ } \text{ } \text{ } \text{Tc} = 25^{\circ} \text{C} \end{split}$$



Application

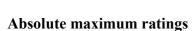
- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Power MOS 7[®] FREDFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Fast intrinsic reverse diode
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration



- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant



Symbol	Parameter		Max ratings	Unit
V_{DSS}	Drain - Source Breakdown Voltage		1200	V
T	Continuous Drain Current	$T_c = 25$ °C	60	
I_{D}	Continuous Drain Current	$T_c = 80$ °C	45	A
I_{DM}	Pulsed Drain current		240	
V_{GS}	Gate - Source Voltage		±30	V
R _{DSon}	Drain - Source ON Resistance		175	mΩ
P_{D}	Maximum Power Dissipation $T_c = 25^{\circ}C$		1250	W
I_{AR}	Avalanche current (repetitive and non repetitive)		22	A
E _{AR}	Repetitive Avalanche Energy		50	m I
E_{AS}	Single Pulse Avalanche Energy		3000	mJ

These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Sy	mbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1200V$	$T_j = 25^{\circ}C$			500	μΑ	
		$V_{GS} = 0V, V_{DS} = 1000V$	$T_j = 125^{\circ}C$			3000		
R_{I}	DS(on)	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 30A$			150	175	mΩ
V	GS(th)	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 10$ mA		3		5	V
I	GSS	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	•			±250	nA

Dynamic Characteristics

·	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		20.6		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		3.08		nF
C_{rss}	Reverse Transfer Capacitance	f=1MHz		0.52		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		748		
Q_{gs}	Gate – Source Charge	$V_{Bus} = 600V$		96		пC
Q_{gd}	Gate – Drain Charge	$I_D = 60A$		480		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C $V_{GS} = 15V$ $V_{Bus} = 800V$ $I_D = 60A$ $R_G = 1.2\Omega$		20		ns
T_{r}	Rise Time			15		
$T_{d(off)}$	Turn-off Delay Time			160		
T_{f}	Fall Time			45		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V$, $V_{Bus} = 800V$ $I_D = 60A$, $R_G = 1.2\Omega$		3.96		T
E_{off}	Turn-off Switching Energy			2.74		mJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		6.26		т
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 800V$ $I_D = 60A, R_G = 1.2\Omega$		3.43		mJ

Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I_S	Continuous Source current		$Tc = 25^{\circ}C$			60	Α
	(Body diode)		$Tc = 80^{\circ}C$			45	А
V_{SD}	Diode Forward Voltage	$V_{GS} = 0V, I_S = -60A$	1			1.3	V
dv/dt	Peak Diode Recovery					18	V/ns
t _{rr}	Reverse Recovery Time	·	$T_j = 25$ °C			320	ns
		$I_S = -60A$ $V_R = 600V$	$T_j = 125$ °C			650	
Q _{rr}	Reverse Recovery Charge	$di_{S}/dt = 400A/\mu s$	$T_j = 25^{\circ}C$		8		μC
			$T_j = 125$ °C		28		μΟ

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

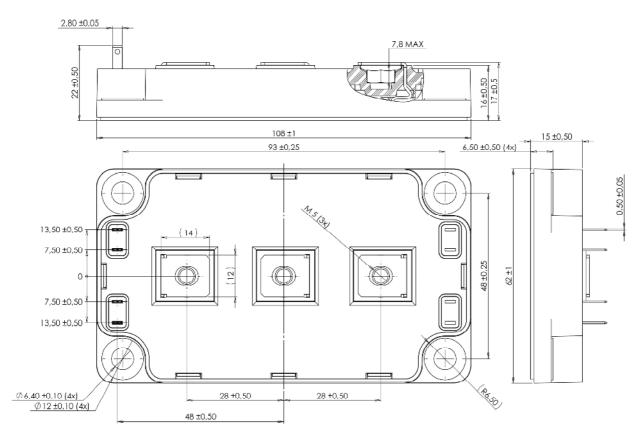
 $I_{S} \leq \text{--} 60 A \qquad \text{di/dt} \leq 700 A/\mu s \qquad V_{R} \leq V_{DSS} \qquad T_{j} \leq 150 ^{\circ} C$



Thermal and package characteristics

Symbol	Characteristic		Min	Typ	Max	Unit	
R_{thJC}	Junction to Case Thermal Resistance					0.1	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range		-40		150		
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	11.111
Wt	Package Weight					300	g

SP6 Package outline (dimensions in mm)



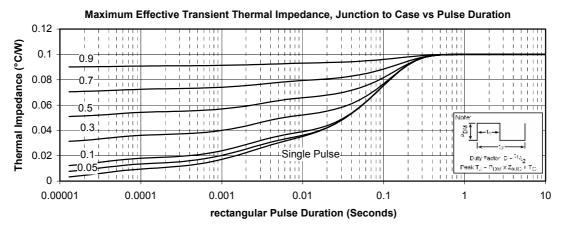
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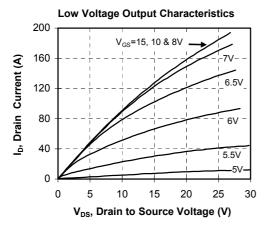
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

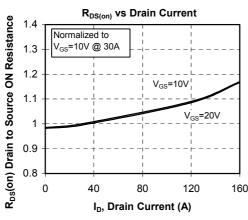
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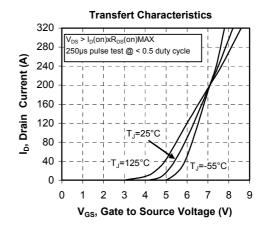


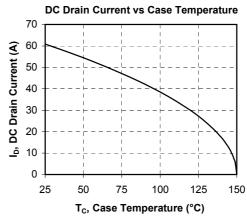
Typical Performance Curve



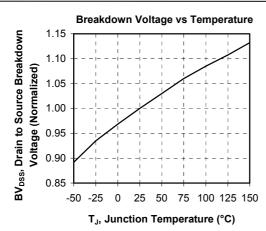


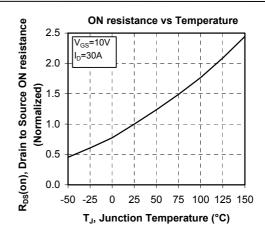


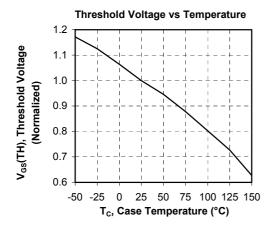


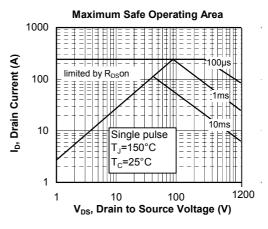


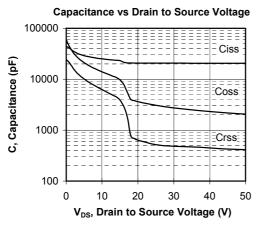


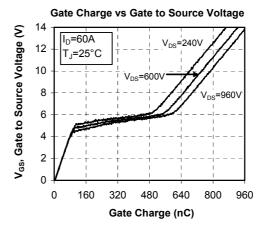




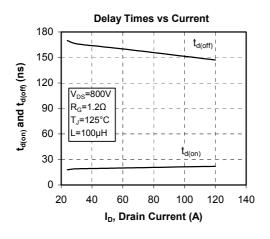


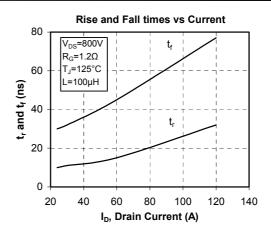


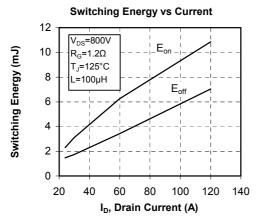


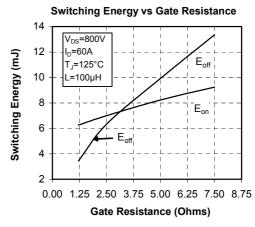


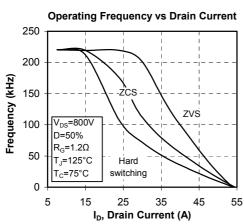


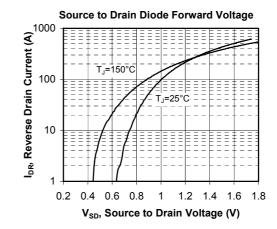














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